

AFE7954 クワッド RF サンプリング 12GSPS D/A コンバータ (DAC)

1 特長

- データシート全体のご請求
- クワッド RF サンプリング 12GSPS DAC
- 最大 RF 信号帯域幅:
 - 4TX: 1200MHz または
 - 2TX: 2400MHz
- RF 周波数範囲: 600MHz ~ 12GHz
- デジタル・ステップ・アッテネータ (DSA):
 - TX: 40dB レンジ、0.125dB ステップ
- シングルまたはデュアル・バンド DUC
- TX に対応する 16 個の NCO
- DAC の内部 PLL / VCO、または DAC サンプル・レートでの外部クロックを選択可能
- SerDes データ・インターフェイス:
 - JESD204B、JESD204C 適合
 - 最高 29.5Gbps を発揮する 8 つの SerDes トランシーバ
 - サブクラス 1 のマルチデバイス同期
- パッケージ: 17mm × 17mm FCBGA、0.8mm ピッチ

2 アプリケーション

- レーダー
- 追尾フロント・エンド
- 防衛無線
- 戦術通信網
- ワイヤレス通信テスト

3 概要

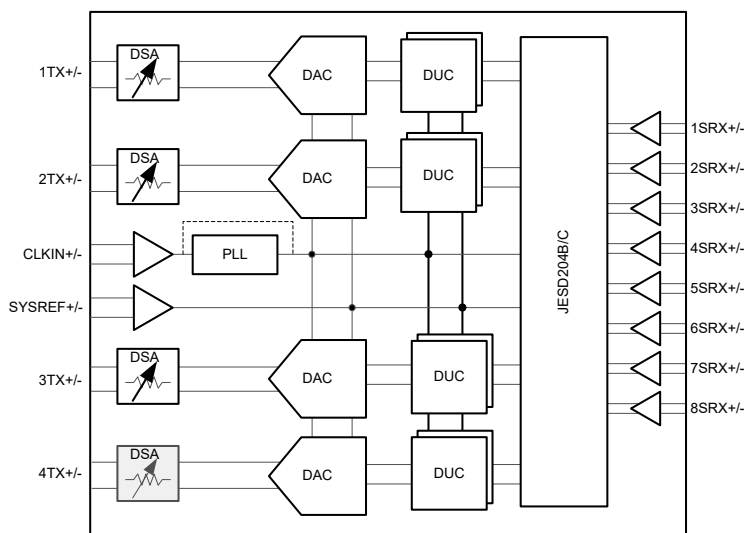
AFE7954 は、高性能、広帯域幅のクワッド・チャンネル RF サンプリング DAC です。このデバイスは、最大 12GHz で動作するため、追加の周波数変換段を必要とせず、L、S、C、X バンドの周波数範囲について直接 RF サンプリングが可能です。こうした密度と柔軟性の向上により、多くのチャンネル数を持つマルチミッション・システムが可能になります。

信号パスは、4 個の DAC (TX) で最大 1200MHz の信号帯域幅、または 2 個の DAC で 2400MHz を実現する、補間およびデジタル昇圧変換オプションをサポートしています。DUC の出力は、2 次ナイキスト動作を拡張する混在モード出力方式で 12GSPS の DAC (D/A コンバータ) を駆動します。DAC 出力は、40dB レンジ、1dB アナログ・ステップ、0.125dB デジタル・ステップの可変ゲイン・アンプ (TX DSA) を内蔵しています。

パッケージ情報

部品番号	パッケージ (1)	パッケージ・サイズ (2)
AFE7954	FC-BGA	17mm × 17mm

- 詳細については、「メカニカル、パッケージ、および注文情報」を参照してください。
- パッケージ・サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



機能ブロック図



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4 概要 (続き)

各レシーバ・チェーンは、3GSPS の ADC (A/D コンバータ) に接続された 25dB レンジの DSA (デジタル・ステップ・アッテネータ) を備えています。各レシーバ・チャネルは、外部または内部の自律的な AGC (自動ゲイン制御) を補助するためのアナログ・ピーク電力検出器とさまざまなデジタル電力検出器、およびデバイスの信頼性を確保するための RF 過負荷検出器を備えています。柔軟なデシメーション・オプションによりデータ帯域幅を最適化でき、FB パスなしの 4 つの RX では最高 1200MHz、2 つの FB パス付き (それぞれ 1200MHz の帯域幅) では最高 600MHz が得られます。

5 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

DATE	REVISION	NOTES
July 2023	*	Initial Release

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Supply Voltage Range	DVDD0P9, VDDT0P9	−0.3	1.2	V
	VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2PLL, VDD1P2PLLCLKREF, VDD1P2FB, VDD1P2FBCML, VDD1P2RXCML	−0.3	1.4	V
	VDD1P8RX, VDD1P8RXCLK, VDD1P8TX, VDD1P8TXDAC, VDD1P8TXENC, VDD1P8PLL, VDD1P8PLLVC0, VDD1P8FB, VDD1P8FBCLK, VDD1P8GPIO, VDDA1P8	−0.5	2.1	V
Pin Voltage Range	{1/2/3/4}TXOUT+/-	−0.5	VDDTX1P8+0.3	V
	REFCLK+/-, SYSREF+/-	−0.3	1.4	V
	{1:8}SRX+/-	−0.3	1.4	V
	GPIO{B/C/D/E}x, SPICLK, SPISDIO, SPISDO, SPISEN, RESETZ, BISTB0, BISTB1	−0.5	VDD1P8GPIO + 0.3	V
	IFORCE, VSENSE	−0.3	VDDCLK1P8 + 0.3	V
	SRDAMUX1, SRDAMUX2	−0.3	VDDA1P8+0.3	V
Peak Input Current	any input		20	mA
T _J	Junction temperature		150	°C
T _{stg}	Storage temperature	−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾	1000	V
		Charged device model (CDM), per ANSI/ESDA/ JEDEC JS-002, all pins	150	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
DVDD0P9, VDDT0P9	Supply voltage 0.9V	0.9	0.925	0.95	V
VDD1P2{RX/TXCLK/TXENC/FB/PLL/ PLLCLKREF/FBCML/RXCML}	Supply voltage 1.2V	1.15	1.2	1.25	V
VDD1P8{RX/RXCLK/TX/TXDAC/ TXENC/PLL/PLLVCO/FB/FBCLK/ GPIO}, VDDA1P8	Supply voltage 1.8V	1.75	1.8	1.85	V
T _A	Ambient temperature	–40		85	°C
T _J	Operating Junction Temperature			110 ⁽¹⁾	°C
	Maximum Operating Junction Temperature	125			°C

- (1) Prolonged use at or above this junction temperature can increase the device failure-in-time (FIT) rate. Refer to [SBAA403 application note](#) for additional details

6.4 Thermal Information AFE79xx

THERMAL METRIC ⁽¹⁾		17mmx17mm FC-BGA	UNIT
		400 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	16.2	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	0.42	°C/W
R _{θJB}	Junction-to-board thermal resistance	4.85	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	0.12	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	4.6	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Transmitter Electrical Characteristics

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DAC _{RES}	DAC resolution			14		bits
f _{RFout}	RF output frequency range	f _{DAC} = 12 GSPS, 1 st Nyquist	600		6000	MHz
		f _{DAC} = 12 GSPS, 2 nd Nyquist	6000		12000	
		f _{DAC} = 9 GSPS, 1 st Nyquist	600		4500	
		f _{DAC} = 9 GSPS, 2 nd Nyquist	4500		9000	
		f _{DAC} = 6 GSPS, 1 st Nyquist	600		3000	
		f _{DAC} = 6 GSPS, 2 nd Nyquist	3000		6000	
P _{max_FS}	Max Full Scale Output Power, max gain 1 tone, at device pins	f _{out} = 850 MHz, f _{DAC} = 5898.24 MSPS, -0.5dBFS		4.2		dBm
		f _{out} = 1800 MHz, f _{DAC} = 5898.24 MSPS, -0.5dBFS		4.6		dBm
		f _{out} = 2600 MHz, f _{DAC} = 8847.36 MSPS, -0.5dBFS		4.0		dBm
		f _{out} = 3500 MHz, -0.5dBFS		3.9		dBm
		f _{out} = 4900 MHz, -0.5dBFS		3.1		dBm
		f _{out} = 3500 MHz, f _{DAC} = 5898.24 MSPS, -0.5dBFS, straight mode		1.0		dBm
		f _{out} = 4900 MHz, f _{DAC} = 5898.24 MSPS, -0.5dBFS, straight mode		0.1		dBm
		f _{out} = 4900 MHz, f _{DAC} = 8847.36 MSPS, -0.5dBFS, straight mode		-0.7		dBm
		f _{out} = 8100 MHz, -0.1dBFS, mixed mode		-2.8		dBm
		f _{out} = 9600 MHz, -0.1dBFS, mixed mode		-4.3		dBm
R _{TERM}	Output termination resistor	Default setting		50		Ω
ATT _{range}	DSA Attenuation range			40		dB
ATT _{step}	DSA Analog Attenuation step			1.0		dB
	DSA Attenuation step accuracy (DNL)	0 < Atten < 40dB, before calibration		±0.2		dB
	DSA Attenuation step accuracy (DNL)	0 < Atten < 40dB, after calibration		±0.1		dB
ATT _{phase-err}	DSA Gain Steps Phase accuracy, any 8dB range	f _{out} = 850MHz ⁽²⁾		±1		deg
		f _{out} = 1800MHz ⁽²⁾		±1		deg
		f _{out} = 2600MHz ⁽²⁾		±1		deg
		f _{out} = 3500MHz ⁽²⁾		±1		deg
		f _{out} = 4900MHz ⁽²⁾		±1		deg
		f _{out} = 8100MHz ⁽²⁾		±2		deg
G _{flat}	Gain flatness	any 20MHz		0.1		dB
		600MHz BW, F _{out} < 4.9G		1.2		

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{A,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
IMD3	3rd Order Intermodulation distortion, 2 tones at $f_{\text{IF}} \pm 10\text{ MHz}$	$f_{\text{out}} = 850\text{MHz}$, -7dBFS each tone		-66		dBc
		$f_{\text{out}} = 1800\text{MHz}$, -7dBFS each tone		-63		dBc
		$f_{\text{out}} = 2600\text{MHz}$, -7dBFS each tone		-62		dBc
		$f_{\text{out}} = 3500\text{MHz}$, -7dBFS each tone		-61		dBc
		$f_{\text{out}} = 4900\text{MHz}$, -7dBFS each tone		-57		dBc
		$f_{\text{out}} = 8100\text{MHz}$, -7dBFS each tone		-55		dBc
		$f_{\text{out}} = 9600\text{MHz}$, -7dBFS each tone		-52		dBc
		$f_{\text{out}} = 850\text{MHz}$, -13dBFS each tone		-74.4		dBc
		$f_{\text{out}} = 1800\text{MHz}$, -13dBFS each tone		-71.1		dBc
		$f_{\text{out}} = 2600\text{MHz}$, -13dBFS each tone		-73		dBc
		$f_{\text{out}} = 3500\text{MHz}$, -13dBFS each tone		-72		dBc
		$f_{\text{out}} = 4900\text{MHz}$, -13dBFS each tone		-67.8		dBc
		$f_{\text{out}} = 8100\text{MHz}$, -13dBFS each tone		-64		dBc
		$f_{\text{out}} = 9600\text{MHz}$, -13dBFS each tone		-68		dBc
SFDR	Spurious Free Dynamic Range (within Nyquist zone)	$f_{\text{out}} = 850\text{ MHz}$		50.8		dBc
		$f_{\text{out}} = 1800\text{ MHz}$		51.9		dBc
		$f_{\text{out}} = 2600\text{ MHz}$		42		dBc
		$f_{\text{out}} = 3500\text{ MHz}$		44		dBc
		$f_{\text{out}} = 4900\text{ MHz}$		46.1		dBc
$f_{\text{S}}/2 - f_{\text{OUT}}$	Interleaving Image	$f_{\text{DAC}} = 5898.24\text{MSPS}$, interleave mode		-51.9		dBc
		$f_{\text{DAC}} = 8847.36\text{ MSPS}$, interleave mode		-46.0		dBc
		$f_{\text{DAC}} = 11796.48\text{MSPS}$, interleave mode		-41		dBc
HD2	2nd Harmonic Distortion (within Nyquist zone)	$f_{\text{out}} = 850\text{ MHz}$		-49		dBc
		$f_{\text{out}} = 1800\text{ MHz}$		-53		dBc
		$f_{\text{out}} = 2600\text{ MHz}$		-50		dBc
		$f_{\text{out}} = 3500\text{ MHz}$		-48		dBc
		$f_{\text{out}} = 4900\text{ MHz}$		-47		dBc
		$f_{\text{out}} = 8100\text{ MHz}$		-50		dBc
		$f_{\text{out}} = 9600\text{ MHz}$		-53		dBc
		$f_{\text{out}} = 850\text{ MHz}$, $A_{\text{OUT}} = -12\text{dBFS}$		-60		dBc
		$f_{\text{out}} = 1800\text{ MHz}$, $A_{\text{OUT}} = -12\text{dBFS}$		-64		dBc
		$f_{\text{out}} = 2600\text{ MHz}$, $A_{\text{OUT}} = -12\text{dBFS}$		-45		dBc
		$f_{\text{out}} = 3500\text{ MHz}$, $A_{\text{OUT}} = -12\text{dBFS}$		-57		dBc
		$f_{\text{out}} = 4900\text{ MHz}$, $A_{\text{OUT}} = -12\text{dBFS}$		-58		dBc
		$f_{\text{out}} = 8100\text{ MHz}$, $A_{\text{OUT}} = -12\text{dBFS}$		-60		dBc
		$f_{\text{out}} = 9600\text{ MHz}$, $A_{\text{OUT}} = -12\text{dBFS}$		-62		dBc

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
HD3	3rd Harmonic Distortion (within Nyquist zone)	$f_{\text{out}} = 850 \text{ MHz}$		-62		dBc
		$f_{\text{out}} = 1800 \text{ MHz}$		-55		dBc
		$f_{\text{out}} = 2600 \text{ MHz}$		-57		dBc
		$f_{\text{out}} = 3500 \text{ MHz}$		-60		dBc
		$f_{\text{out}} = 4900 \text{ MHz}$		-54		dBc
		$f_{\text{out}} = 8100 \text{ MHz}$		-54		dBc
		$f_{\text{out}} = 9600 \text{ MHz}$		-56		dBc
		$f_{\text{out}} = 850 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-80		dBc
		$f_{\text{out}} = 1800 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-79		dBc
		$f_{\text{out}} = 2600 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-77		dBc
		$f_{\text{out}} = 3500 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-77		dBc
		$f_{\text{out}} = 4900 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-78		dBc
		$f_{\text{out}} = 8100 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-82		dBc
		$f_{\text{out}} = 9600 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-80		dBc
HDn, n >= 4	Harmonic Distortion n >= 4 (within Nyquist zone)	$f_{\text{out}} = 850 \text{ MHz}$		-81		dBc
		$f_{\text{out}} = 1800 \text{ MHz}$		-88		dBc
		$f_{\text{out}} = 2600 \text{ MHz}$		-86		dBc
		$f_{\text{out}} = 3500 \text{ MHz}$		-79		dBc
		$f_{\text{out}} = 4900 \text{ MHz}$		-86		dBc
		$f_{\text{out}} = 8100 \text{ MHz}$		-87		dBc
		$f_{\text{out}} = 9600 \text{ MHz}$		-85		dBc
		$f_{\text{out}} = 850 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-93		dBc
		$f_{\text{out}} = 1800 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-98		dBc
		$f_{\text{out}} = 2600 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-84		dBc
		$f_{\text{out}} = 3500 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
		$f_{\text{out}} = 4900 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
		$f_{\text{out}} = 8100 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
		$f_{\text{out}} = 9600 \text{ MHz}, A_{\text{OUT}} = -12\text{dBFS}$		-87		dBc
SFDR +/- 250 MHz	Spurious Free Dynamic Range within +/- 250 MHz	$f_{\text{out}} = 850 \text{ MHz}$		68.5		dBc
		$f_{\text{out}} = 1800 \text{ MHz}$		79.4		dBc
		$f_{\text{out}} = 2600 \text{ MHz}$		77		dBc
		$f_{\text{out}} = 3500 \text{ MHz}$		75		dBc
		$f_{\text{out}} = 4900 \text{ MHz}$		76		dBc
		$f_{\text{out}} = 8100 \text{ MHz}$		61		dBc
		$f_{\text{out}} = 9600 \text{ MHz}$		64		dBc
$f_s/4$	Fixed Spur	$f_{\text{DAC}} = 5898.24\text{MSPS}$		-64		dBFS
		$f_{\text{DAC}} = 8847.36\text{MSPS}$		-75		dBFS
		$f_{\text{DAC}} = 11796.48\text{MSPS}$		-67		dBFS
$f_s/2$	Fixed Spur	$f_{\text{DAC}} = 5898.24\text{MSPS}$		-49		dBFS
		$f_{\text{DAC}} = 8847.36\text{MSPS}$		-48		dBFS
		$f_{\text{DAC}} = 11796.48 \text{ MSPS}$		-48		dBFS

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{A,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$3*f_s/4$	Fixed Spur	2nd Nyquist, $f_{\text{DAC}} = 5898.24\text{MSPS}$		-76		dBFS
		2nd Nyquist, $f_{\text{DAC}} = 8847.36\text{MSPS}$		-89		dBFS
		2nd Nyquist, $f_{\text{DAC}} = 11796.48\text{MSPS}$		-63		dBFS
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier $f_{\text{out}} = 0.85\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-68.5		dBc
		Atten=20dB, Pout=-13dBFS		-67.2		dBc
		Atten=28dB, Pout=-13dBFS		-64.5		dBc
		Atten=39dB, Pout=-13dBFS		-53.9		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier $f_{\text{out}} = 1.8425\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-70.7		dBc
		Atten=20dB, Pout=-13dBFS		-68.3		dBc
		Atten=28dB, Pout=-13dBFS		-62.9		dBc
		Atten=39dB, Pout=-13dBFS		-52.0		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier $f_{\text{out}} = 2.6\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-71		dBc
		Atten=20dB, Pout=-13dBFS		-68		dBc
		Atten=28dB, Pout=-13dBFS		-62		dBc
		Atten=39dB, Pout=-13dBFS		-51.3		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier $f_{\text{out}} = 3.5\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-70		dBc
		Atten=20dB, Pout=-13dBFS		-67		dBc
		Atten=28dB, Pout=-13dBFS		-60		dBc
		Atten=39dB, Pout=-13dBFS		-49.8		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, LTE 20MHz E-TM1.1 carrier $f_{\text{out}} = 4.9\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-68.8		dBc
		Atten=20dB, Pout=-13dBFS		-65.9		dBc
		Atten=28dB, Pout=-13dBFS		-60.6		dBc
		Atten=39dB, Pout=-13dBFS		-49.5		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier $f_{\text{out}} = 2.6\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-65		dBc
		Atten=20dB, Pout=-13dBFS		-62		dBc
		Atten=20dB, Pout=-13dBFS		-55		dBc
		Atten=39dB, Pout=-13dBFS		-44.3		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier $f_{\text{out}} = 3.5\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-64		dBc
		Atten=20dB, Pout=-13dBFS		-59		dBc
		Atten=28dB, Pout=-13dBFS		-52		dBc
		Atten=39dB, Pout=-13dBFS		-41.1		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier $f_{\text{out}} = 4.9\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-64.1		dBc
		Atten=20dB, Pout=-13dBFS		-60.4		dBc
		Atten=28dB, Pout=-13dBFS		-53.5		dBc
		Atten=39dB, Pout=-13dBFS		-42.5		dBc
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier $f_{\text{out}} = 8.1\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-58		dBc
		Atten=20dB, Pout=-13dBFS		-53		dBc
		Atten=28dB, Pout=-13dBFS		-46		dBc
		Atten=39dB, Pout=-13dBFS		-36		dBc

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{A,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
ACPR _{1xcarr}	ACPR - 1 carrier, NR 100MHz E-TM1.1 carrier $f_{\text{out}} = 9.6\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-57		dBc
		Atten=20dB, Pout=-13dBFS		-50		dBc
		Atten=28dB, Pout=-13dBFS		-42		dBc
		Atten=39dB, Pout=-13dBFS		-31		dBc
EVM	Error Vector Magnitude, 1x 20MHz E-TM3.1/3.1a, no ref. clock noise	$F_{\text{out}} = 0.85\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.2		%
		$F_{\text{out}} = 1.8425\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.3		%
		$F_{\text{out}} = 2.6\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.28		%
		$F_{\text{out}} = 3.5\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.38		%
		$F_{\text{out}} = 4.9\text{ GHz}$, $P_{\text{OUT}} = -13\text{dBFS}$		0.4		%
NSD _{dBFS}	Noise Spectral Density 20MHz offset $f_{\text{OUT}} = 0.85\text{ GHz}$	Atten=0dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-157.6		dBFS/Hz
		Atten=20dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-153.3		dBFS/Hz
		Atten=28dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-147.9		dBFS/Hz
		Atten=39dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-136.9		dBFS/Hz
NSD _{dBFS}	Noise Spectral Density 20MHz offset $f_{\text{OUT}} = 1.8\text{ GHz}$	Atten=0dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-158.4		dBFS/Hz
		Atten=20dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-152.2		dBFS/Hz
		Atten=28dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-145.6		dBFS/Hz
		Atten=39dB, $f_{\text{DAC}} = 5898.24\text{MSPS}$, Pout=-13dBFS		-134.6		dBFS/Hz
NSD _{dBFS}	Noise Spectral Density 20MHz offset $f_{\text{OUT}} = 2.6\text{ GHz}$	Atten=0dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-157		dBFS/Hz
		Atten=20dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-151		dBFS/Hz
		Atten=28dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-144		dBFS/Hz
		Atten=39dB, $f_{\text{DAC}} = 8847.36\text{MSPS}$, Pout=-13dBFS		-133.0		dBFS/Hz
NSD _{dBFS}	Noise Spectral Density 20MHz offset $F_{\text{out}} = 3.5\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-158		dBFS/Hz
		Atten=20dB, Pout=-13dBFS		-150		dBFS/Hz
		Atten=28dB, Pout=-13dBFS		-143		dBFS/Hz
		Atten=39dB, Pout=-13dBFS		-131.8		dBFS/Hz

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{A,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
NSD _{dBFS}	Noise Spectral Density 20MHz offset $F_{\text{out}} = 4.9\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-155.5		dBFS/ Hz
		Atten=20dB, Pout=-13dBFS		-147.8		dBFS/ Hz
		Atten=28dB, Pout=-13dBFS		-140.8		dBFS/ Hz
		Atten=39dB, Pout=-13dBFS		-129.6		dBFS/ Hz
NSD _{dBFS}	Noise Spectral Density 50MHz offset $F_{\text{out}} = 8.1\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-153		dBFS/ Hz
		Atten=20dB, Pout=-13dBFS		-147		dBFS/ Hz
		Atten=28dB, Pout=-13dBFS		-140		dBFS/ Hz
		Atten=39dB, Pout=-13dBFS		-129		dBFS/ Hz
NSD _{dBFS}	Noise Spectral Density 50MHz offset $F_{\text{out}} = 9.6\text{ GHz}$	Atten=0dB, Pout=-13dBFS		-152		dBFS/ Hz
		Atten=20dB, Pout=-13dBFS		-147		dBFS/ Hz
		Atten=28dB, Pout=-13dBFS		-140		dBFS/ Hz
		Atten=39dB, Pout=-13dBFS		-129		dBFS/ Hz
S22	Output Return Loss, <6GHz, +/- fc * 10%	with matching		-17		dB
	Output Return Loss, >8GHz, +/- fc * 10%	with matching		-10		dB
Isolation	Near Channel: 1TXOUT to 2TXOUT or 3TXOUT to 4TXOUT ⁽¹⁾	$f_{\text{out}} = 900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-49		dB
		$f_{\text{out}} = 1850\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-59		dB
		$f_{\text{out}} = 2600\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-65		dB
		$f_{\text{out}} = 3500\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-66		dB
		$f_{\text{out}} = 4900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-60		dB
		$f_{\text{out}} = 900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-90		dB
		$f_{\text{out}} = 1850\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-91		dB
		$f_{\text{out}} = 2600\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-93		dB
		$f_{\text{out}} = 3500\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-94		dB
		$f_{\text{out}} = 4900\text{ MHz}$, $f_{\text{DAC}} = 8847.36\text{MSPS}$, straight mode		-83		dB

6.5 Transmitter Electrical Characteristics (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS below 6GHz and 1474.56MSPS above 6GHz, $f_{\text{DAC}} = 11796.48\text{MSPS}$; PLL clock mode below 6GHz output frequency and External clock mode above 6GHz output frequency; interleave mode for 1st Nyquist, non-interleave mix mode for 2nd Nyquist, nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 16.22Gbps, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
PN _{TXADD}	Additive Phase Noise External Clock Mode ⁽³⁾	$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 100\text{Hz}$		-88		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 1\text{kHz}$		-102		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 10\text{kHz}$		-110		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 100\text{kHz}$		-123		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 1\text{MHz}$		-136		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 10\text{MHz}$		-143		dBc/Hz
		$f_{\text{out}} = 9.6\text{GHz}$, $f_{\text{OFFSET}} = 100\text{MHz}$		-146		dBc/Hz

- (1) Measured with differential 50 ohm across TxP/M. The DC bias to 1.8V to each TxP/M at each pin remains and is not removed. Other external components on the TX paths are disconnected.
- (2) After DSA calibration procedure
- (3) Single side band, input clock phase noise subtracted.

6.6 PLL/VCO/Clock Electrical Characteristics

Typical values at TA = +25°C, full temperature range is T_{A,MIN} = -40°C to T_{J,MAX} = +110°C; Reference clock input frequency 491.52MHz (unless otherwise noted), f_{DAC} = f_{VCO}, f_{OUT} = f_{DAC}/4, normalized to f_{VCO}.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _{VCO1}	VCO1 min frequency				7.2	GHz
	VCO1 max frequency		7.68			GHz
f _{VCO2}	VCO2 min frequency				8.8	GHz
	VCO2 max frequency		9.1			GHz
f _{VCO3}	VCO3 min frequency				9.7	GHz
	VCO3 max frequency		10.24			GHz
f _{VCO4}	VCO4 min frequency				11.6	GHz
	VCO4 max frequency		12.08			GHz
DIV _{DAC}	DAC sample rate divider			1, 2 or 3		
DIV _{FBAD} C	ADC sample rate divider from DAC sample rate			1, 2, 3, 4, 6 or 8		
DIV _{RXAD} C	ADC sample rate divider			1, 2, 3, 4, 6 or 8		
PN _{VCO}	Closed Loop Phase Noise F _{PLL} = 11.79848 GHz F _{REF} =491.52MHz	600kHz		-113		dBc/Hz
		800kHz		-116		dBc/Hz
		1MHz		-119		dBc/Hz
		1.8MHz		-125		dBc/Hz
		5MHz		-133		dBc/Hz
		50MHz		-141		dBc/Hz
	Closed Loop Phase Noise F _{PLL} =8.84736 GHz F _{REF} =491.52MHz	600kHz		-114		dBc/Hz
		800kHz		-118		dBc/Hz
		1MHz		-120		dBc/Hz
		1.8MHz		-127		dBc/Hz
		5MHz		-135		dBc/Hz
		50MHz		-142		dBc/Hz
	Closed Loop Phase Noise F _{PLL} = 9.8403 GHz F _{REF} =491.52MHz	600kHz		-113		dBc/Hz
		800kHz		-116		dBc/Hz
		1MHz		-119		dBc/Hz
		1.8MHz		-125		dBc/Hz
		5MHz		-134		dBc/Hz
		50MHz		-140		dBc/Hz
	Closed Loop Phase Noise F _{PLL} = 7.86432GHz F _{REF} =491.52MHz	600kHz		-116		dBc/Hz
		800kHz		-119		dBc/Hz
		1MHz		-122		dBc/Hz
		1.8MHz		-127		dBc/Hz
		5MHz		-136		dBc/Hz
		50MHz		-143		dBc/Hz
F _{rms}	Clock PLL integrated phase error ⁽¹⁾	f _{PLL} =11.79848 GHz, [1KHz, 100MHz]		-43.4		dBc/Hz
		f _{PLL} =8.8536 GHz, [1KHz, 100MHz]		-47.6		dBc/Hz
		f _{PLL} =9.8304 GHz, [1KHz, 100MHz]		-46.2		dBc/Hz
f _{PFD}	PFD frequency		100		500	MHz
PN _{pll_flat}	Normalized PLL flat Noise	f _{VCO} = 11796.48MHz		-226.5		dBc/Hz
F _{REF}	Input Clock frequency		0.1		12	GHz

6.6 PLL/VCO/Clock Electrical Characteristics (continued)

Typical values at $T_A = +25^{\circ}\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^{\circ}\text{C}$ to $T_{J,\text{MAX}} = +110^{\circ}\text{C}$; Reference clock input frequency 491.52MHz (unless otherwise noted), $f_{\text{DAC}} = f_{\text{VCO}}$, $f_{\text{OUT}} = f_{\text{DAC}}/4$, normalized to f_{VCO} .

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{SS}	Input Clock level		0.6		1.8	Vppdiff
Coupling				AC Coupling Only		
	REFCLK input impedance ⁽²⁾	Parallel resistance		100		Ω
		Parallel capacitance		0.5		pF

(1) Single Sideband, not including the reference clock contribution

(2) Refer to S11 data available from TI for impedance vs frequency

6.7 Digital Electrical Characteristics

Typical values at TA = +25°C, full temperature range is T_{A,MIN} = -40°C to T_{J,MAX} = +110°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CML SerDes Inputs [8:1]SRX+/-						
V _{SRDIFF}	SerDes Receiver Input Amplitude	differential	100		1200	mVpp
V _{SRCOM}	SerDes Input Common Mode		0.4	0.5	0.6	V
Z _{SRdiff}	SerDes Internal Differential Termination ⁽¹⁾			100		Ω
F _{SerDes}	SerDes Bit Rate	Full rate mode	19		29.5	Gbps
		Half rate mode	9.5		16.25	Gbps
		Quarter rate mode	4.75		8.125	Gbps
	Insertion Loss Tolerance ⁽²⁾	Serdes supply = 1.8V		25		dB
TJ	Total Jitter Tolerance				0.42	UI
CMOS I/O: GPIO{B/C/D/E}x, SPICLK, SPIDIO, SPISDO, SPISEN, RESETZ, BISTB0, BISTB1						
V _{IH}	High-Level Input Voltage		0.6×VDD1 P8GPIO			V
V _{IL}	Low-Level Input Voltage		0.4×VDD1 P8GPIO			V
I _{IH}	High-Level Input Current		-250		250	μA
I _{IL}	Low-Level Input Current		-250		250	μA
C _L	CMOS input capacitance			2		pF
V _{OH}	High-Level Output Voltage		VDD1P8G PIO-0.2			V
V _{OL}	Low-Level Output Voltage				0.2	V
Differential Inputs: SYSREF+/- Mode A						
Clock _{MODE}				PLL Clock Mode Only		
F _{SYSREFMAX}	SYSREF Input Frequency Maximum			40		MHz
V _{SWINGSRMAX}	SYSREF Input Swing Maximum			1.8		Vppdiff ⁽³⁾
V _{SWINGSRMIN}	SYSREF Input Swing Minimum	f _{REF} < 500MHz		0.3		Vppdiff ⁽³⁾
V _{SWINGSRMIN}	SYSREF Input Swing Minimum	f _{REF} > 500MHz		0.6		Vppdiff ⁽³⁾
V _{COMSRMAX}	SYSREF Input Common Mode Voltage Maximum			0.8		V
V _{COMSRMIN}	SYSREF Input Common Mode Voltage Minimum			0.6		V
Z _T	Input termination	differential		100 ⁽¹⁾		Ω
C _L	Input capacitance	Each pin to GND		0.5		pF
LVDS Inputs: 0SYNCIN+/- and 1SYNCIN+/-						
V _{ICOM}	Input Common Voltage			1.2		V
V _{ID}	Differential Input Voltage swing			450		Vppdiff ⁽³⁾
Z _T	Input termination	differential		100		Ω
LVDS Outputs: 0SYNCOUT+/- and 1SYNCOUT+/-						
V _{OCOM}	Output Common Voltage			1.2		V
V _{OD}	Differential Output Voltage swing			500		Vppdiff ⁽³⁾
Z _T	Internal Termination			100		Ω

(1) SYSREF termination is programmable between 100Ω, 150Ω and 300Ω

(2) Loss tolerance is bump to bump from STX to SRX

- (3) V_{ppdiff} is the difference between the maximum differential voltage (positive value) and minimum differential voltage (negative value).

6.8 Power Supply Electrical Characteristics

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{A,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 500MSPS, RX Output Rate = 500MSPS, $f_{\text{DAC}} = 9000\text{MSPS}$ interleave mode; $f_{\text{ADC}} = 3000\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 20Gbps; unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 1: 4TX TX Dual Band: 96x Int, TX Rate 125 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 1.85 + 2.15\text{ GHz}$ JESD: 8/10 coding, 20Gbps TX: 2-16-16-1		564		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC + VDD1P8GPIO + VDDA1P8			274		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLVC0			71		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			953		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			1747		mA
P_{diss}	Power Dissipation			4396		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 2: 4TX TX Single Band: 24x Int, TX Rate 500 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 8/10 coding, 20Gbps TX: 4-8-4-1		570		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC + VDD1P8GPIO + VDDA1P8			382		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLVC0			72		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			967		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			2172		mA
P_{diss}	Power Dissipation			5011		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 3: 4TX TX Single Band: 12x Int, TX Rate 1 GSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 8/10 coding, 20Gbps TX: 8-8-2-1		571		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC + VDD1P8GPIO + VDDA1P8			495		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLVC0			72		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			969		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			2465		mA
P_{diss}	Power Dissipation			5490		mW

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 500MSPS, RX Output Rate = 500MSPS, $f_{\text{DAC}} = 9000\text{MSPS}$ interleave mode; $f_{\text{ADC}} = 3000\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 20Gbps; unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 4: 4TX TX Single Band: 8x Int, TX Rate 1500 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 64/66 coding, 24.75Gbps TX: 8-8-2-1		569		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC + VDD1P8GPIO + VDDA1P8			521		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLCO			73		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			981		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			2719		mA
P_{diss}	Power Dissipation			5786		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 5: 2TX TX Single Band: 4x Int, TX Rate 3000 MSPS $f_{\text{DAC}} = 12\text{ GSPS}$, $f_{\text{TX}} = 2.75\text{ GHz}$ JESD: 64/66 coding, 24.75Gbps TX: 8-4-1-1		297		mA
	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC + VDD1P8GPIO + VDDA1P8			446		mA
	Group 3C: VDD1P8PLL + VDD1P8PLLCO			72		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			544		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			1575		mA
P_{diss}	Power Dissipation			3577		mW
I_{VDD1P8}	Group 3A: VDD1P8FB + VDD1P8RX + VDD1P8TX	Mode 6: Same as Mode 5 in Sleep mode with Sleep pin pulled high.		96		mA
I_{VDD1P8}	Group 3B: VDD1P8FBCLK + VDD1P8RXCLK + VDD1P8TXDAC + VDD1P8GPIO + VDDA1P8			330		mA
I_{VDD1P8}	Group 3C: VDD1P8PLL + VDD1P8PLLCO			16		mA
I_{VDD1P2}	Group 2: VDD1P2FB, VDD1P2RX, VDD1P2TXCLK, VDD1P2TXENC, VDD1P2FBCML, VDD1P2RXCML and VDD1P2PLLCLKREF			48		mA
I_{VDD0P9}	Group 1A: DVDD0P9 + VDDT0P9			302		mA
P_{diss}	Power Dissipation			1132		mW

6.9 Timing Requirements

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,MIN} = -40^\circ\text{C}$ to $T_{J,MAX} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS, $f_{DAC} = 8847.36\text{MSPS}$; $f_{ADC} = 2949.12\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 24.33Gbps; unless otherwise noted.

		MIN	NOM	MAX	UNIT
Timing: SYSREF+/-					
$t_s(\text{SYSREF})$	Setup Time, SYSREF+/- Valid to Rising Edge of CLK+/-		50		ps
$t_h(\text{SYSREF})$	Hold Time, SYSREF+/- Valid after Rising Edge of CLK+/-		50		ps
Timing: Serial ports					
$t_s(\text{SENB})$	Setup Time, SENB to Rising Edge of SCLK			15	ns
$t_h(\text{SENB})$	Hold Time, SENB after last Rising Edge of SCLK ⁽¹⁾			$5 + t_{\text{SCLK}}$	ns
$t_s(\text{SDIO})$	Setup Time, SDIO valid to Rising Edge of SCLK			15	ns
$t_h(\text{SDIO})$	Hold Time, SDIO valid after Rising Edge of SCLK			5	ns
$t_{\text{(SCLK)_W}}$	Minimum SCLK period: registers write			25	ns
$t_{\text{(SCLK)_R}}$	Minimum SCLK period: registers read			50	ns
$t_{\text{d(data_out)}}$	Minimum Data Output delay after Falling Edge of SCLK			0	ns
	Maximum Data Output delay after Falling Edge of SCLK			15	ns
t_{RESET}	Minimum RESETZ Pulse Width		1		ms

(1) SDEN\ need to be held one more extra clock cycle with the last SCLK edge

6.10 Switching Characteristics

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{A,\text{MIN}} = -40^\circ\text{C}$ to $T_{J,\text{MAX}} = +110^\circ\text{C}$; TX Input Rate = 491.52MSPS, $f_{\text{DAC}} = 8847.36\text{MSPS}$; $f_{\text{ADC}} = 2949.12\text{MSPS}$; nominal power supplies; 1 tone at -1 dBFS; DSA Attenuation = 0dB; SerDes rate = 24.33Gbps; unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
TX Channel Latency						
	SerDes Receiver Analog Delay	Full rate		2.8		ns
$t_{\text{JESD TX}}$	JESD to TX output Latency	LMFSHd=2-8-8-1, 368.64 MSPS input rate, 24x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		152		interface clock cycles ⁽¹⁾
		LMFSHd=8-16-4-1, 491.52 MSPS 24x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		176		
		LMFSHd=4-16-8-1, 245.76 MSPS 48x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		124		
		LMFSHd=2-16-16-1, 122.88 MSPS 96x Interpolation, Serdes rate = 16.22Gbps (JESD204C)		97		

(1) Interface clock cycles is the period of the digital interface sample rate, e.g. 1GSPS = 1ns.

7 Device and Documentation Support

7.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](https://www.ti.com) のデバイス製品フォルダを開いてください。「更新の通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

7.2 サポート・リソース

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7.3 Trademarks

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7.4 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

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7.5 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

8 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
AFE7954IABJ	Active	Production	FCBGA (ABJ) 400	90 JEDEC TRAY (5+1)	Yes	SNAGCU SNAGCU	Level-3-260C-168 HR	-40 to 85	AFE7954I
AFE7954IABJ.B	Active	Production	FCBGA (ABJ) 400	90 JEDEC TRAY (5+1)	-	Call TI	Call TI	-40 to 85	
AFE7954IALK	Active	Production	FCBGA (ALK) 400	90 JEDEC TRAY (5+1)	No	Call TI	Level-3-220C-168 HR	-40 to 85	AFE7954 SNPB
AFE7954IALK.B	Active	Production	FCBGA (ALK) 400	90 JEDEC TRAY (5+1)	-	Call TI	Call TI	-40 to 85	

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

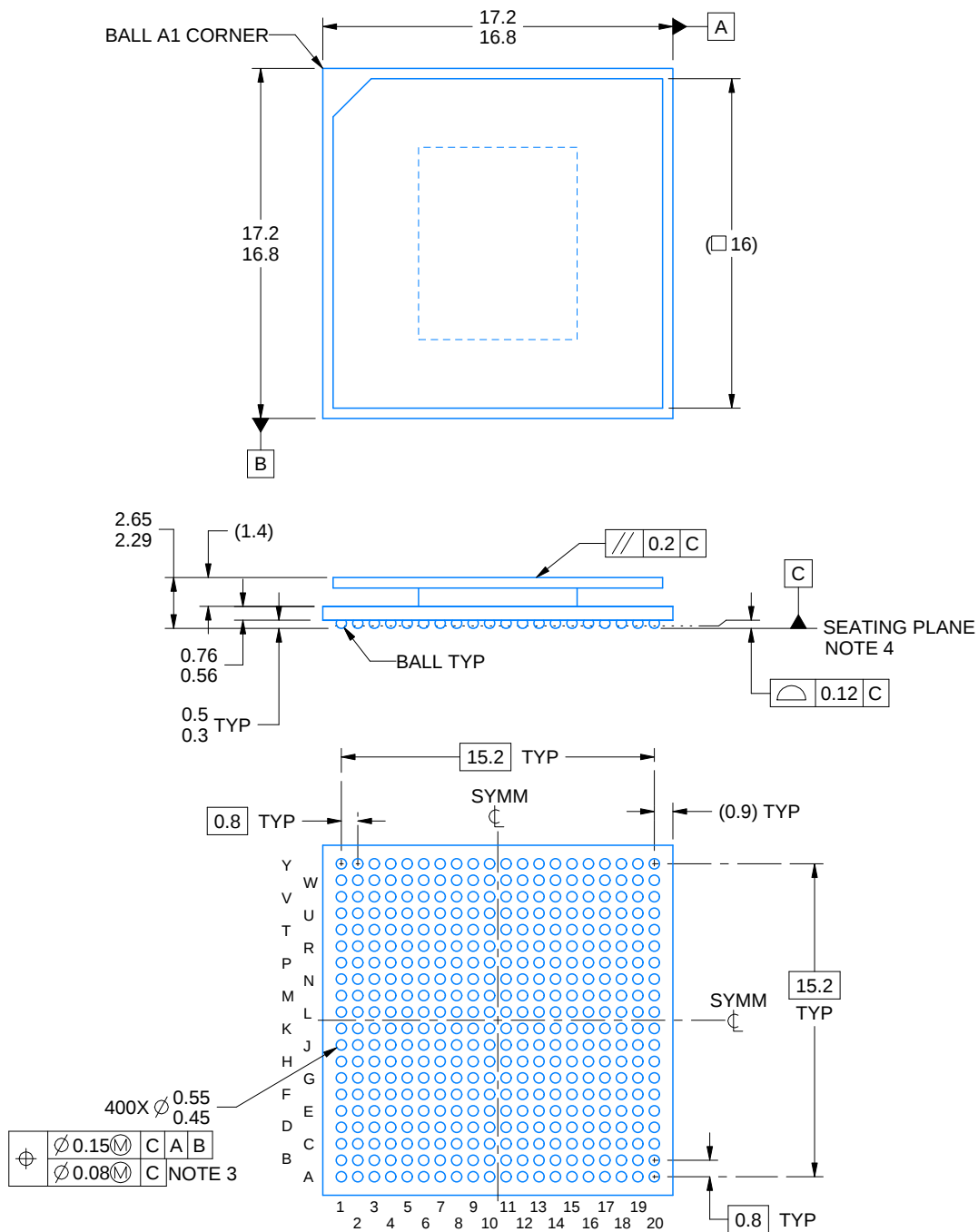
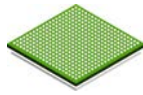
⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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4221311/D 03/2023

NOTES:

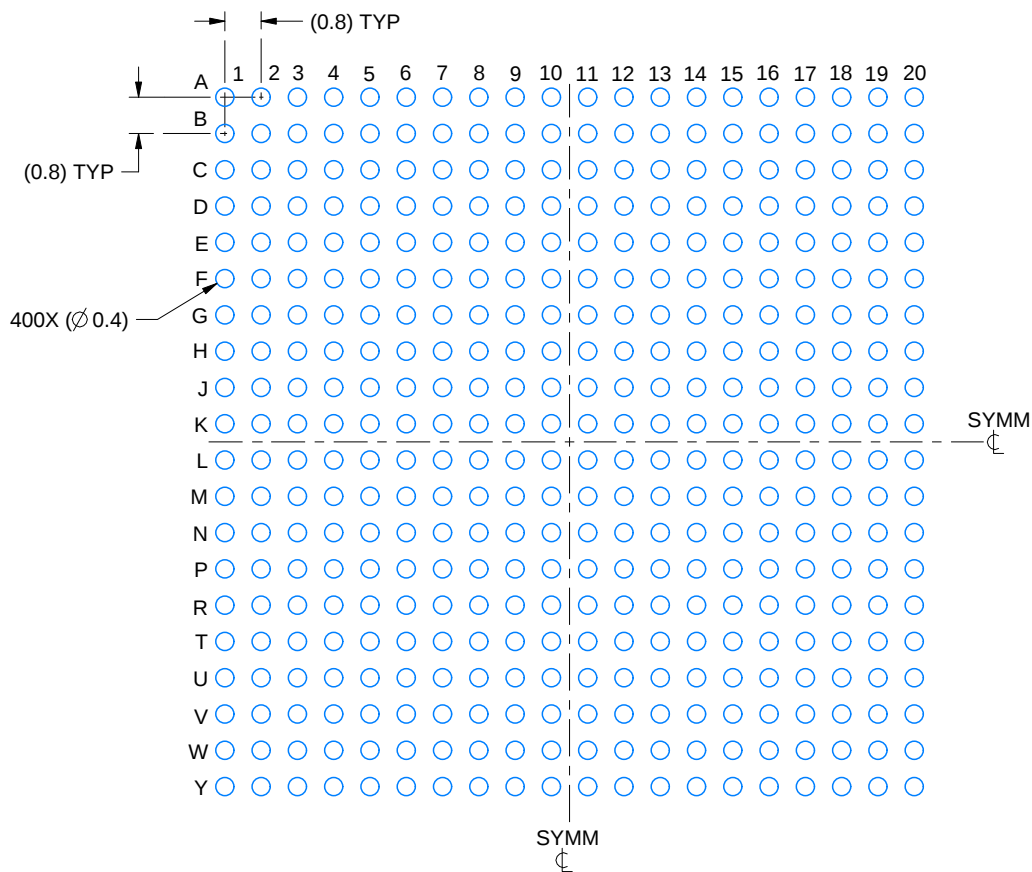
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Dimension is measured at the maximum solder ball diameter, parallel to primary datum C.
4. Primary datum C and seating plane are defined by the spherical crowns of the solder balls.
5. The lids are electrically floating (e.g. not tied to GND).

EXAMPLE BOARD LAYOUT

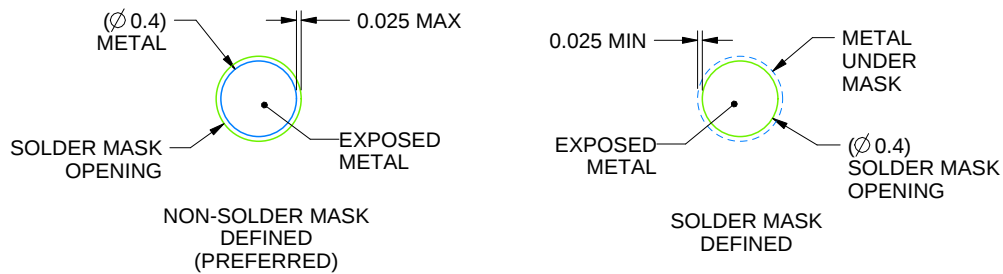
ABJ0400A

FCBGA - 2.65 mm max height

BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X



SOLDER MASK DETAILS
NOT TO SCALE

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NOTES: (continued)

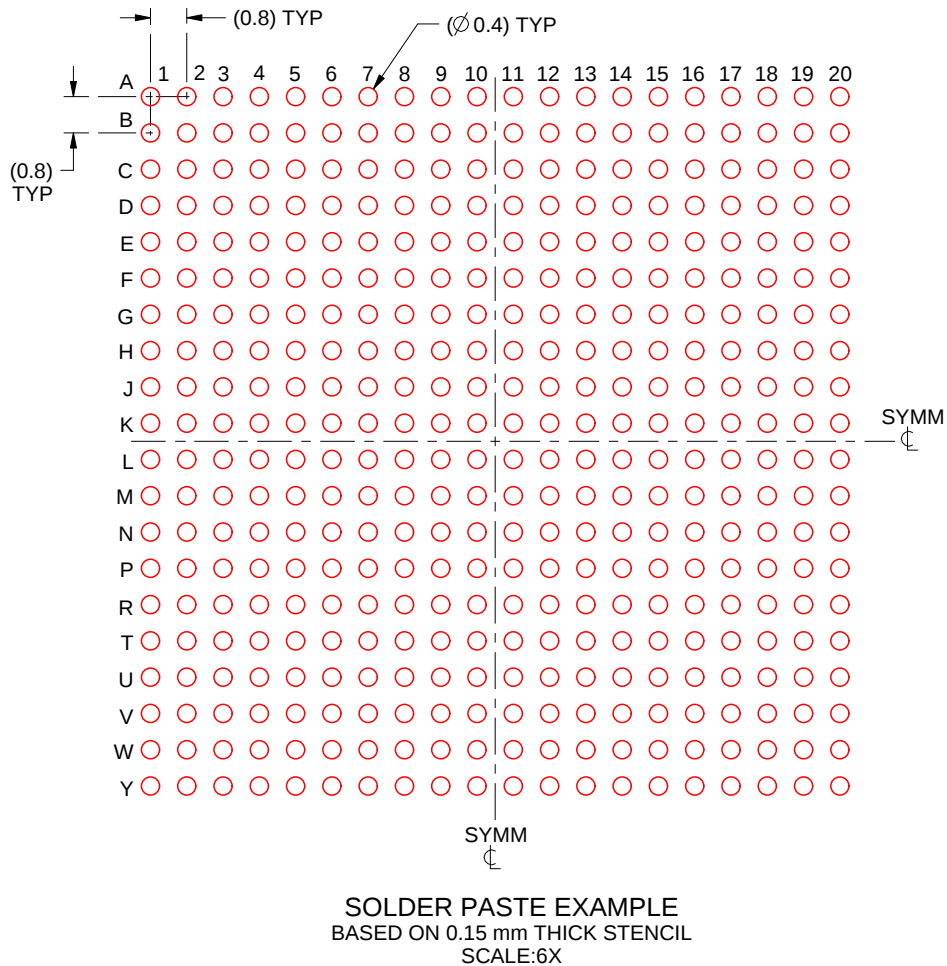
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SPRU811 (www.ti.com/lit/spru811).

EXAMPLE STENCIL DESIGN

ABJ0400A

FCBGA - 2.65 mm max height

BALL GRID ARRAY



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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

FCBGA - 2.65 mm max height

Technical drawing of a 400X ball grid array (BGA) component. The drawing includes three views: a top view, a side view, and a ball grid array view.

Top View: Shows a square component with dimensions 17.2 x 17.2 mm (16.8 x 16.8 mm). A corner is labeled "BALL A1 CORNER". A dashed square indicates a 16 mm square area.

Side View: Shows the component's profile with dimensions 2.65 x 2.29 mm (1.4 mm). It includes a "BALL TYP" (ball type) and a "SEATING PLANE NOTE 4".

Ball Grid Array View: Shows a 20x20 grid of balls. The grid dimensions are 15.2 mm x 15.2 mm. The ball pitch is 0.8 mm. The ball diameter is 0.55 mm. The ball height is 0.45 mm. The grid is labeled with letters Y through A and numbers 1 through 20.

Notes:

- 400X Ø 0.55 0.45
- 50X C A B
- 18X C NOTE 3
- SYMM
- SEATING PLANE NOTE 4

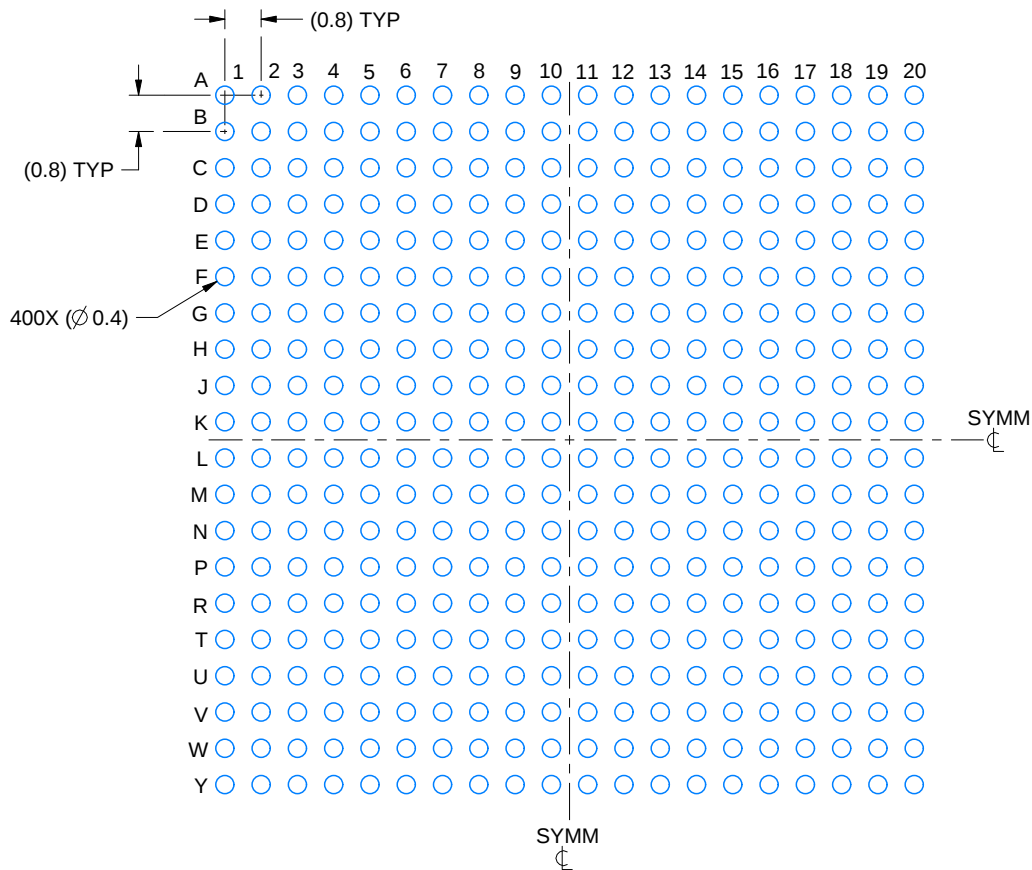
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Dimension is measured at the maximum solder ball diameter, parallel to primary datum C.
4. Primary datum C and seating plane are defined by the spherical crowns of the solder balls.
5. Pb-Free die bump and SnPb solder ball.
6. The lids are electrically floating (e.g. not tied to GND).

EXAMPLE BOARD LAYOUT

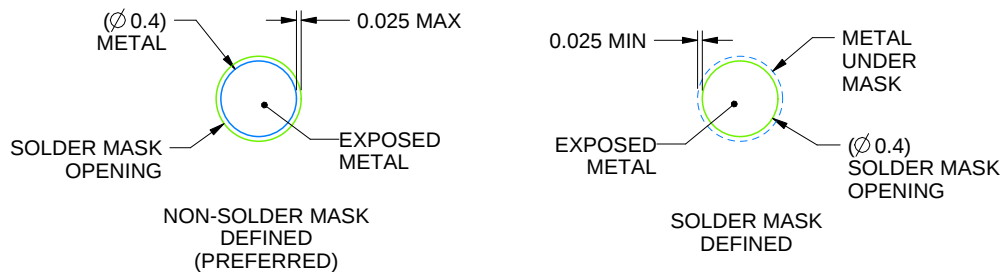
ALK0400A

FCBGA - 2.65 mm max height

BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X



SOLDER MASK DETAILS
NOT TO SCALE

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NOTES: (continued)

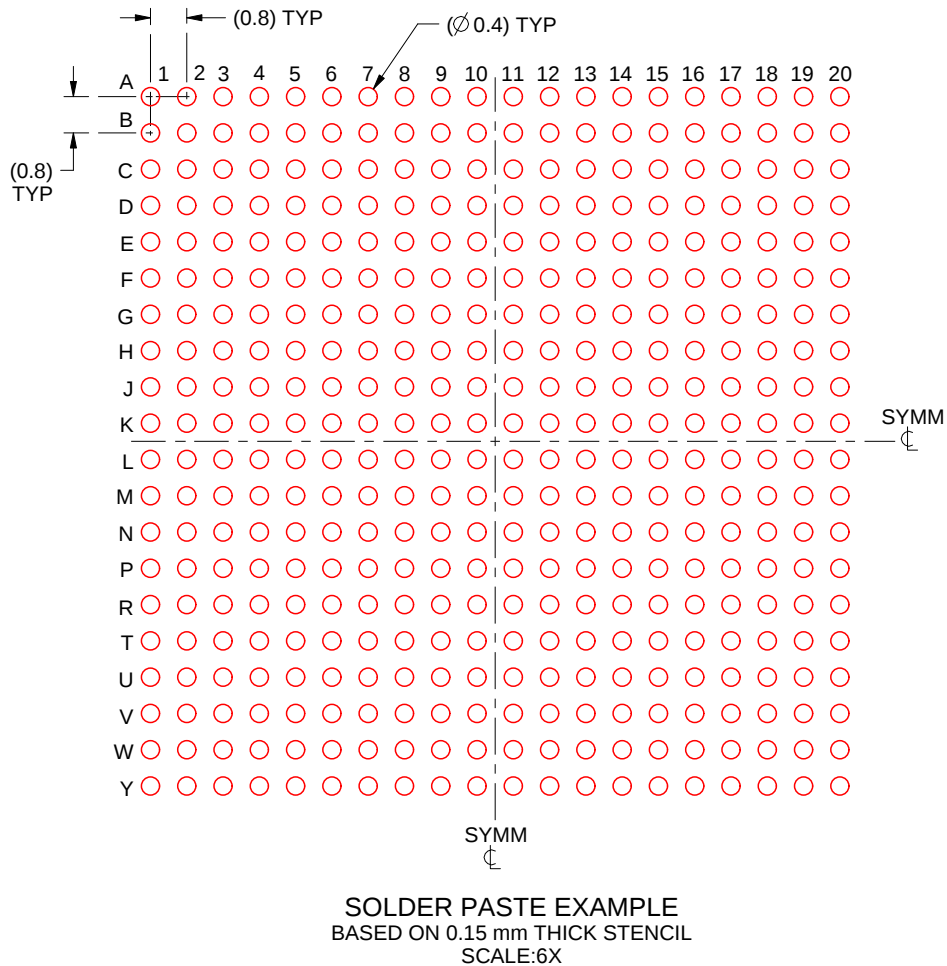
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SPRU811 (www.ti.com/lit/spru811).

EXAMPLE STENCIL DESIGN

ALK0400A

FCBGA - 2.65 mm max height

BALL GRID ARRAY



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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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